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 Operate With 3-V to 5.5-V V_{CC} Supply Operate Up To 1 Mbit/s 	DB, DW, OR F (TOP	PW PACKAGE VIEW)
• Low Standby Current 1 μA Typ		20 FORCEOFF
• External Capacitors 4 \times 0.1 μ F	C1+[]2	19 V _{CC}
 Accept 5-V Logic Input With 3.3-V Supply 	V+[]3	18 GND
Latch-Up Performance Exceeds 100 mA Per	C1-[] 4	17 DOUT1
JESD 78, Class II	C2+[]5	16 RIN1
 RS-232 Bus-Pin ESD Protection Exceeds 	C2-[]6	15 ROUT1
	V-[] 7	14 🛛 FORCEON
±15 kV Using Human-Body Model (HBM)	DOUT2 🛛 8	13 DIN1
Applications	RIN2	12 DIN2
 Battery-Powered Systems, PDAs, 		11 INVALID
Notebooks, Laptops, Palmtop PCs, and	······································	

description/ordering information

Hand-Held Equipment

The SN65C3223 and SN75C3223 consist of two line drivers, two line receivers, and a dual charge-pump circuit with \pm 15-kV ESD protection pin to pin (serial-port connection pins, including GND). The devices provide the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low and EN is high, both drivers and receivers are shut off, and the supply current is reduced to 1 μ A. Disconnecting the serial port or turning off the peripheral drivers causes auto-powerdown to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than –2.7 V or has been between –0.3 V and 0.3 V for less than 30 μ s. Refer to Figure 4 for receiver input levels.

TA	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		Tube of 25	SN75C3223DW	7500000
	SOIC – DW	Reel of 2000	SN75C3223DWR	75C3223
0°C to 70°C	SSOP – DB	Reel of 2000	SN75C3223DBR	CA3223
		Tube of 70	SN75C3223PW	
	TSSOP – PW	Reel of 2000	SN75C3223PWR	CA3223
	0010 014	Tube of 25	SN65C3223DW	
	SOIC – DW	Reel of 2000	SN65C3223DWR	65C3223
–40°C to 85°C	SSOP – DB	Reel of 2000	SN65C3223DBR	CB3223
	7000D DW	Tube of 70	SN65C3223PW	0.00000
	TSSOP – PW	Reel of 2000	SN65C3223PWR	CB3223

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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Function Tables

			EACH DRIVER		
		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	Х	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

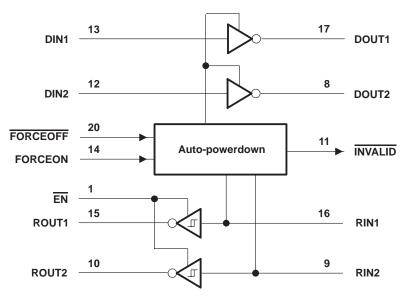
H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER

	INP	PUTS	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	Х	Н
н	L	Х	L
Х	Н	Х	Z
Open	L	No	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} (see Note 1) Positive output supply voltage range, V+ (see Note 1) Negative output supply voltage range, V– (see Note 1)	0.3 V to 7 V 0.3 V to -7 V
Supply voltage difference, V+ – V– (see Note 1)	
Input voltage range, VI: Driver, FORCEOFF, FORCEON, EN	$\dots \dots \dots \dots -0.3 \text{ V to 6 V}$
Receiver	–25 V to 25 V
Output voltage range, V _O : Driver	13.2 V to 13.2 V
Receiver, INVALID	\dots –0.3 V to V _{CC} + 0.3 V
Package thermal impedance, θ_{JA} (see Notes 2 and 3): DB package	
	58°C/W
	83°C/W
Operating virtual junction temperature, T _J	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

- 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 6)

				MIN	NOM	MAX	UNIT
	cc Supply voltage		$V_{CC} = 3.3 V$	3	3.3	3.6	
Vcc			$V_{CC} = 5 V$	4.5	5	5.5	V
		r and control high-level input voltage $DIN, \overline{EN}, \overline{FORCEOFF}, \overline{VCC} = 3.3 V$ FORCEON $V_{CC} = 5 V$	$V_{CC} = 3.3 V$	2			V
VIH	Driver and control high-level input voltage		$V_{CC} = 5 V$	2.4			V
VIL	Driver and control low-level input voltage	DIN, EN, FORCEOFF, FORCEO	NC			0.8	V
	Driver and control input voltage	DIN, EN, FORCEOFF, FORCEO	NC	0		5.5	N/
VI	Receiver input voltage			-25		25	V
т.			SN65C3223	-40		85	°C
Τ _Α	Operating free-air temperature		SN65C3223	0		70	U

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP‡	MAX	UNIT	
Ц	Input leakage current	EN, FORCEOFF, FORCEON			±0.01	±1	μA
		Auto-powerdown disabled	$\frac{\text{No load,}}{\text{FORCEOFF, FORCEON at V}_{\text{CC}}}$		0.3	1	mA
lcc	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
		Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

[‡] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TE	ST CONDITION	S	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to G	ND		5	5.4		V
VOL	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to G	DOUT at $R_L = 3 k\Omega$ to GND			-5.4		V
Iн	High-level input current	VI = VCC				±0.01	±1	μΑ
۱ _{IL}	Low-level input current	V _I at GND				±0.01	±1	μΑ
		V _{CC} = 3.6 V,	VO = 0 V			±35	±60	
los	Short-circuit output current‡	V _{CC} = 5.5 V,	VO = 0 V			±35	±90	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_{O} = \pm 2 V$		300	10M		Ω
		FORCEOFF = GND	$V_{O} = \pm 12 V$,	V_{CC} = 3 V to 3.6 V			±25	
loff	Output leakage current	FORGEOFF = GND	$V_{O} = \pm 10 V$,	V_{CC} = 4.5 V to 5.5 V			±25	μΑ

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡] Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
	Maximum data rate $R_L = 3 k\Omega$, (see Figure 1) One DOUT switching	C _L = 1000 pF		250				
		C _L = 250 pF,	V_{CC} = 3 V to 4.5 V	1000			kbit/s	
		one beer entering	C _L = 1000 pF,	V_{CC} = 4.5 V to 5.5 V	1000			
tsk(p)	Pulse skew [§]	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF},$	$R_L = 3 \ k\Omega$ to 7 $k\Omega$,	See Figure 2		300		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V _{CC} = 3.3 V, R _L = 3 kΩ to 7 kΩ	C _L = 150 pF to 1000	pF	18		150	V/µs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

\$ Pulse skew is defined as $|tp_{LH} - tp_{HL}|$ of each channel of the same device. NOTE 4: Test conditions are C1-C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2-C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} – 0.6	V _{CC} – 0.1		V
VOL	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
N/	Desitive spin picture three held welters	V _{CC} = 3.3 V		1.6	2.4	
VIT+	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.9	2.4	V
	No. 2010 and the stand thread add and the set	V _{CC} = 3.3 V	0.6	1.1		
VIT-	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.4		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT} –)			0.5		V
loff	Output leakage current	$\overline{EN} = V_{CC}$		±0.05	±10	μΑ
r _i	Input resistance	$V_I = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4)

PARAMETER		TEST (TEST CONDITIONS		MAX	UNIT
^t PLH	Propagation delay time, low- to high-level output	CL= 150 pF,	See Figure 3	150		ns
^t PHL	Propagation delay time, high- to low-level output	C _L = 150 pF,	See Figure 3	150		ns
t _{en}	Output enable time	C _L = 150 pF, See Figure 4	$R_L = 3 k\Omega$,	200		ns
^t dis	Output disable time	C _L = 150 pF, See Figure 4	RL = 3 kΩ,	200		ns
^t sk(p)	Pulse skew [‡]	See Figure 3		50		ns

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡]Pulse skew is defined as |t_{PLH} – t_{PHL}| of each channel of the same device.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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AUTO-POWERDOWN SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

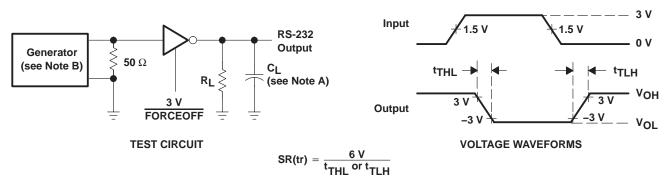
	PARAMETER	TEST C	ONDITIONS	MIN	MAX	UNIT
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$		2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-2.7		V
V _{T(invalid)}	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-0.3	0.3	V
VOH	INVALID high-level output voltage	$\frac{I_{OH} = -1 \text{ mA}}{FORCEOFF} = V_{CC}$	FORCEON = GND,	V _{CC} – 0.6		V
VOL	INVALID low-level output voltage	$\frac{I_{OL} = 1.6 \text{ mA}}{FORCEOFF} = V_{CC}$	FORCEON = GND,		0.4	V

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER						
^t valid	Propagation delay time, low- to high-level output	1	μs			
^t invalid	Propagation delay time, high- to low-level output	30	μs			
t _{en}	Supply enable time	100	μs			

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

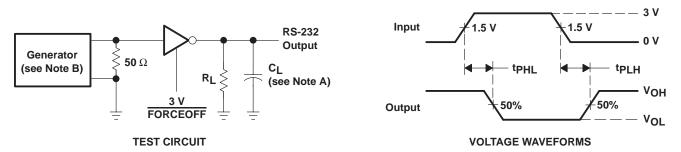
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



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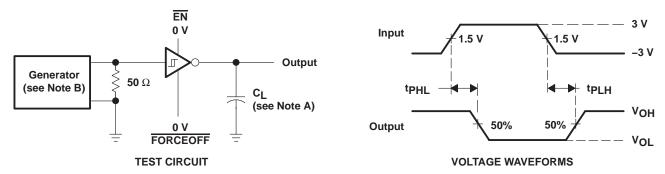
PARAMETER MEASUREMENT INFORMATION



NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

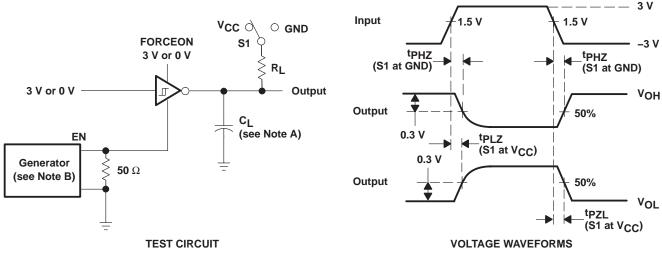
Figure 2. Driver Pulse Skew



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10 \text{ ns}$. $t_f \le 10 \text{ ns}$.

Figure 3. Receiver Propagation Delay Times



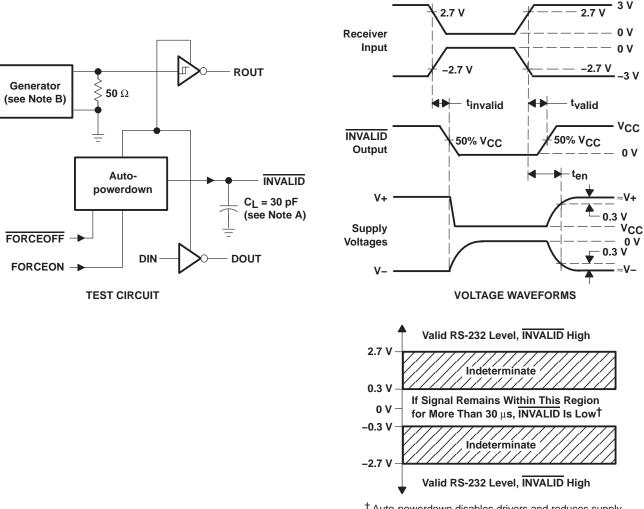
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_{O} = 50 \Omega$, 50% duty cycle, $t_{f} \le 10$ ns. $t_{f} \le 10$ ns.

Figure 4. Receiver Enable and Disable Times



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PARAMETER MEASUREMENT INFORMATION

 † Auto-powerdown disables drivers and reduces supply current to 1 $\mu A.$

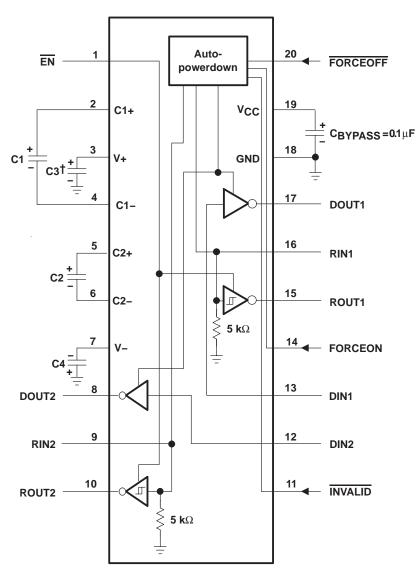
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time



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APPLICATION INFORMATION

 † C3 can be connected to V_CC or GND. NOTE A: Resistor values shown are nominal.

V _{CC} vs CAPACITOR VALUES									
Vcc	C1	C2, C3, C4							
3.3 V ± 0.3 V 5 V ± 0.5 V	0.1 μF 0.047 μF	0.1 μF 0.33 μF							
3 V to 5.5 V	0.1 μ F	0.47 μF							

Figure 6. Typical Operating Circuit and Capacitor Values





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65C3223DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	(6) NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3223	Samples
SN65C3223DBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3223	Samples
SN65C3223DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C3223	Samples
SN65C3223DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C3223	Samples
SN65C3223PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3223	Samples
SN65C3223PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3223	Samples
SN75C3223DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA3223	Samples
SN75C3223DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75C3223	Samples
SN75C3223PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA3223	Samples
SN75C3223PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA3223	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C3223DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN65C3223DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN65C3223PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN75C3223DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN75C3223DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN75C3223PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

30-Dec-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C3223DBR	SSOP	DB	20	2000	853.0	449.0	35.0
SN65C3223DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN65C3223PWR	TSSOP	PW	20	2000	853.0	449.0	35.0
SN75C3223DBR	SSOP	DB	20	2000	853.0	449.0	35.0
SN75C3223DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN75C3223PWR	TSSOP	PW	20	2000	853.0	449.0	35.0

PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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